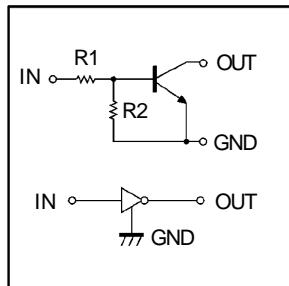


Digital transistors (built-in resistors)

- **Features**

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- 2) The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 3) Only the on/off conditions need to be set for operation, making device design easy.
- 4) Higher mounting densities can be achieved.

DTC115EKA



EIAJ: SC—59

- Absolute maximum ratings($T_a=25^{\circ}\text{C}$)

Parameter	symbol	Limits	unit
Supply voltage	V_{cc}	50	V
Input voltage	V_{IN}	-40 ~ +10	V
Output current	I_o	20	mA
	$I_{C(\text{Max.})}$	100	
Power dissipation	P_d	200	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55~+150	°C

- Electrical characteristics($T_a=25^{\circ}\text{C}$)

Parameter	symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(\text{off})}$	—	—	0.5	V	$V_{cc}=5\text{V}, I_o=100\mu\text{A}$
	$V_{I(\text{on})}$	3	—	—		$V_{o}= 0.3\text{V}, I_o=1\text{mA}$
Output Voltage	$V_{O(\text{on})}$	—	0.1	0.3	V	$I_o/I_i= 5\text{mA}/0.25\text{mA}$
Input current	I_i	—	—	0.15	mA	$V_i = 5\text{V}$
Output current	$I_{O(\text{off})}$	—	—	0.5	μA	$V_{cc}=50\text{V}, V_i = 0\text{V}$
DC current gain	G_i	82	—	—	—	$V_{o}= 5\text{V}, I_o= 5\text{mA}$
Input resistance	R_i	70	100	130	KΩ	—
Resistance ratio	R_2 / R_1	0.8	1	1.2	—	—
Transition frequency	f_T	—	250	—	MHz	$V_{ce}=10\text{V}, I_e= -5\text{mA}, f = 100\text{MHz}^*$

*Transition frequency of the device